## NSN 5961-00-471-4915

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-471-4915 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.097 inches **Overall Diameter:** 1.250 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 2.50 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 75.0 degrees celsius ambient air **Special Features:** voltage **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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